
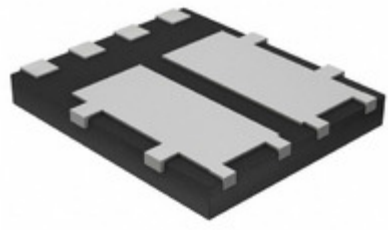
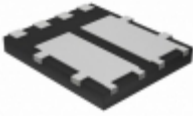
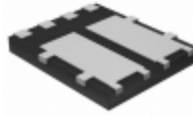
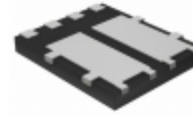
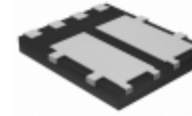
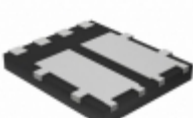
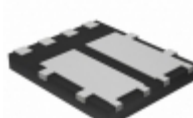
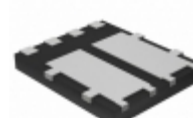
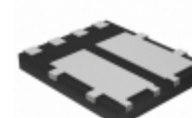
	<h2 style="color: red;">NVMFD5877NLWFT1G</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NVMFD5877NLWFT1G</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET 2N-CH 60V 6A SO8FL</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">NVMFD5877NLWFT1G.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 834 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NVMFD5877NLWFT1G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET 2N-CH 60V 6A SO8FL
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	834 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	3.2W
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-DFN (5x6) Dual Flag (SO8FL-Dual-Asymmetrical)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A
Rds On (Max) @ Id, Vgs	39 mOhm @ 7.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	540pF @ 25V
Verpackung	Tape & Reel (TR)

NVMFD5877NLWFT1G ist neu im Original, Suche NVMFD5877NLWFT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVMFD5877NLWFT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVMFD5877NLWFT1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NVMFD5877NLWFT3G</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 6A SO8FL</p>	 <p><b>NVMFD5877NLT1G</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 6A 8SOIC</p>	 <p><b>NVMFD5C446NT1G</b> AMI Semiconductor / ON Semiconductor 40V 2.9 MOHM T8 SO8FL DUA</p>	 <p><b>NVMFD5877NLT3G</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 6A 8SOIC</p>
 <p><b>NVMFD5875NLT3G</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p>	 <p><b>NVMFD5C446NLWFT1G</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 40V 145A SO8FL</p>	 <p><b>NVMFD5875NLWFT1G</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p>	 <p><b>NVMFD5C446NWFT1G</b> AMI Semiconductor / ON Semiconductor 40V 2.9 MOHM T8 SO8FL DUA</p>

### heiße Teile

Mehr

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FJX945OTF	GRM0225C1E8R1DDAEL	GRM1556P1H7R8CZ01D	GRM32NR71H564KA01L	HF30ACC575018-T
IDT7202LA120LB	ISL6313BIRZ	LC4032V-75TN48I	LM2931AD-5.0R2G	LM5114AMFX
LT140SC-TE84L	MAX5024SASA	MDS35D-14	MT6223AA/A	NVMD3P03
NVMD3P03R2G	NVMD4N03	NVMD6N04	NVMFD5853NLT1G	NVMFD5877NLT3G
NVMFS4C01NWFT1G	NVMFS4C05N	NVMFS5113PLT1G	NVMFS5830NLWFT1G	NVMFS5885NLT3G
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QM300HH-24-203	S-1000C35-M5T1G	SI4816BDY-T1-E3	SKR135F08	SN74AHC1G08DBVRG4
TK11245BMCL	TMS320F206PZ	TR3D226M035C0300	TSG40N50DV	XCR3064A-10VQ100C

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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